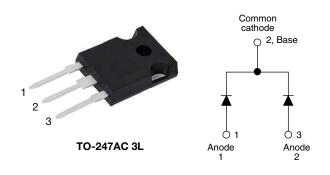
Vishay Semiconductors

Ultrafast Rectifier, 2 x 15 A FRED Pt[®]



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PRIMARY CHARACTERISTICS									
I _{F(AV)}	2 x 15 A								
V _R	200 V								
V _F at I _F	0.85 V								
t _{rr} typ.	See Recovery table								
T _J max.	175 °C								
Package	TO-247AC 3L								
Circuit configuration	Common cathode								

FEATURES

- Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and gualified according to JEDEC[®]-JESD 47



RoHS COMPLIANT HALOGEN FREE

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

VS-MUR3020WT... is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage		V _{RRM}		200	V				
Average rectified forward current	per leg	I		15					
Average rectilied forward current	total device	I _{F(AV)}	Rated V_R , T_C = 150 °C	30	А				
Non-repetitive peak surge current per leg		I _{FSM}	t _p = 10 ms	200	A				
Peak repetitive forward current per leg		I _{FM}	Rated V_R , square wave, 20 kHz, $T_C = 150 \ ^\circ C$	30					
Operating junction and storage temperatures		T _J , T _{Stg}		-65 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-					
Forward voltage	VF	I _F = 15 A	-	-	1.05	V				
	۷F	I _F = 15 A, T _J = 150 °C	-	-	0.85					
D		$V_{R} = V_{R}$ rated	-	-	10					
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	500	μA					
Junction capacitance	CT	V _R = 200 V	-	55	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	12	-	nH				

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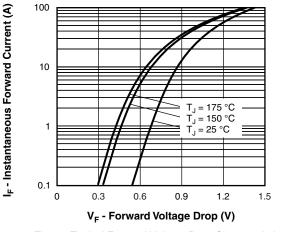
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ di}_F/\text{dt} =$	50 A/µs, V _R = 30 V	-	-	35				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	22	-	ns			
		T _J = 125 °C		-	39	-				
Pools receivers ourrent	1	T _J = 25 °C	l _F = 15 A di _F /dt = 200 A/µs	-	1.6	-	- A			
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 160 \text{ V}$	-	4.1	-				
Reverse recovery charge	0	T _J = 25 °C	·n	-	19	-				
	Q _{rr}	T _J = 125 °C		-	90	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C				
Thermal resistance, junction to case per leg	R _{thJC}		-	-	1.5					
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	40	°C/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-					
Weight			-	6.0	-	g				
weight			-	0.21	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AC 3L	MUR3020WT							



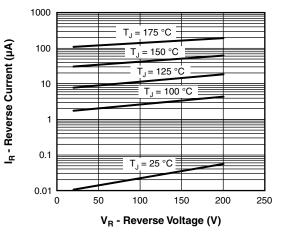
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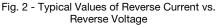


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Fig. 1 - Typical Forward Voltage Drop Characteristics





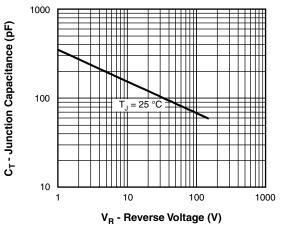


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

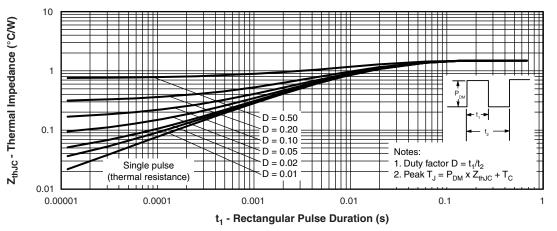
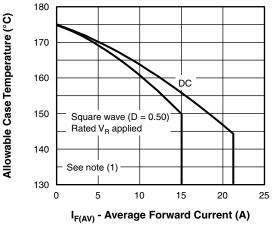
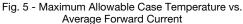


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics







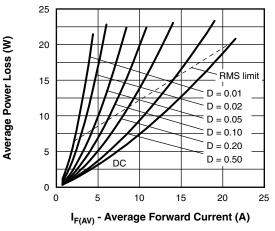
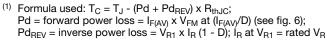


Fig. 6 - Forward Power Loss Characteristics

Note



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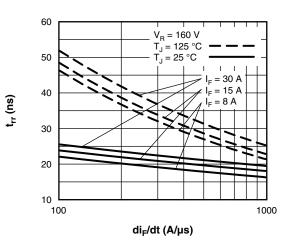


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt

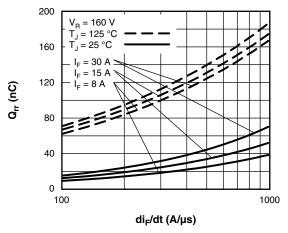


Fig. 8 - Typical Stored Charge vs. di_F/dt

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VS-MUR3020WT-N3

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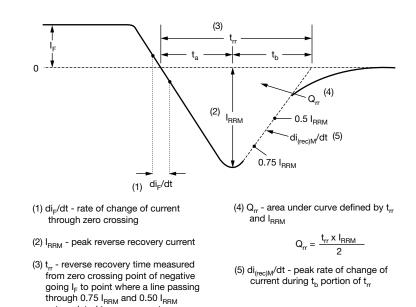


Fig. 9 - Reverse Recovery Waveform and Definitions

extrapolated to zero current.

ORDERING INFORMATION TABLE

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Device code	VS-	MUR	30	20	νт	-N3
			(3)	(4)	(5)	6
	····	\bigcirc	lay Sem	\bigcirc	\bigcirc	\bigcirc
	2 -	Ultra	afast Ml	JR serie	s (TO-2	247AC)
	3 -	Curi	rent ratii	ng (30 =	= 30 A)	
	4 -	Volt	age rati	ng (20 =	= 200 V)	
	5 -	WT	= cente	r tap (dı	ual) TO-	247
	6 -	Env	ironmer	ital digit	:	
		-N3	= halog	en-free,	RoHS-	complia

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MUR3020WT-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS								
Dimensions www.vishay.com/doc?96138								
Part marking information	www.vishay.com/doc?95007							

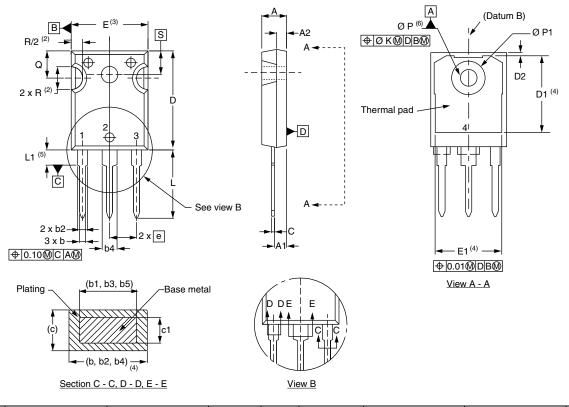
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Vishay Semiconductors

TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			Е	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØР	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	BSC	
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension Q

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